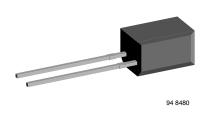
# Vishay Semiconductors



# Silicon PIN Photodiode, RoHS Compliant



### **FEATURES**

Package type: leaded

· Package form: side view

• Dimensions (in mm): 5 x 4 x 6.8

• Radiant sensitive area (in mm<sup>2</sup>): 7.5

· High radiant sensitivity

Daylight blocking filter matched with 940 nm emitters

• Fast response times

• Angle of half sensitivity:  $\varphi = \pm 65^{\circ}$ 

 Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC





## **DESCRIPTION**

BPW41N is a PIN photodiode with high speed and high radiant sensitivity in a black, side view plastic package with daylight blocking filter. Filter bandwidth is matched with 900 nm to 950 nm IR emitters.

### **APPLICATIONS**

- · High speed detector for infrared radiation
- Infrared remote control and free air data transmission systems, e.g. in combination with TSALxxxx series IR emitters

PRODUCT SUMMARY			
COMPONENT	I <sub>ra</sub> (μΑ)	φ (deg)	λ <sub>0.5</sub> (nm)
BPW41N	45	± 65	870 to 1050

### Note

Test condition see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
BPW41N	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	Side view	

### Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	60	V	
Power dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>V</sub>	215	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	°C	
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C	
Soldering temperature	t ≤ 5 s	T <sub>sd</sub>	260	°C	
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm <sup>2</sup>	R <sub>thJA</sub>	350	K/W	

### Note

 $T_{amb}$  = 25 °C, unless otherwise specified



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BASIC CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Breakdown voltage	I <sub>R</sub> = 100 μA, E = 0	$V_{(BR)}$	60			V
Reverse dark current	V <sub>R</sub> = 10 V, E = 0	I <sub>ro</sub>		2	30	nA
Diada sanasitanas	V <sub>R</sub> = 0 V, f = 1 MHz, E = 0	C <sub>D</sub>		70		pF
Diode capacitance	V <sub>R</sub> = 3 V, f = 1 MHz, E = 0	C <sub>D</sub>		25	40	pF
Open circuit Voltage	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	Vo		350		mV
Temperature coefficient of Vo	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	$TK_Vo$		- 2.6		mV/K
Short circuit current	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$	l <sub>k</sub>		38		μΑ
Temperature coefficient of I <sub>k</sub>	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	TK <sub>lk</sub>		0.1		%/K
Reverse light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}, \ V_R = 5 \text{ V}$	I <sub>ra</sub>	43	45		μΑ
Angle of half sensitivity		φ		± 65		deg
Wavelength of peak sensitivity		$\lambda_{p}$		950		nm
Range of spectral bandwidth		λ <sub>0.5</sub>		870 to 1050		nm
Noise equivalent power	$V_R = 10 \text{ V}, \lambda = 950 \text{ nm}$	NEP		4 x 10 <sup>-14</sup>		W/√ Hz
Rise time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t <sub>r</sub>		100		ns
Fall time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t <sub>f</sub>		100		ns

#### Note

T<sub>amb</sub> = 25 °C, unless otherwise specified

## **BASIC CHARACTERISTICS**

 $T_{amb}$  = 25 °C, unless otherwise specified

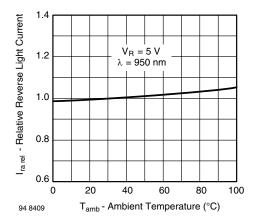


Fig. 1 - Relative Reverse Light Current vs. Ambient Temperature

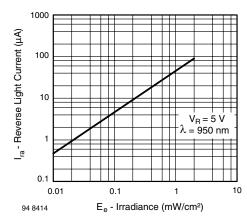


Fig. 2 - Reverse Light Current vs. Irradiance

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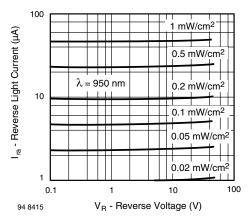


Fig. 3 - Reverse Light Current vs. Reverse Voltage

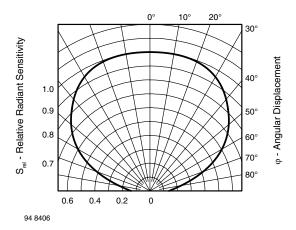


Fig. 6 - Relative Radiant Sensitivity vs. Angular Displacement

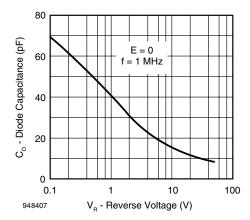


Fig. 4 - Diode Capacitance vs. Reverse Voltage

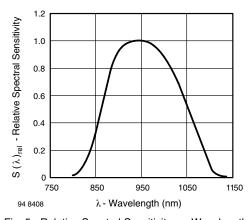
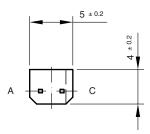


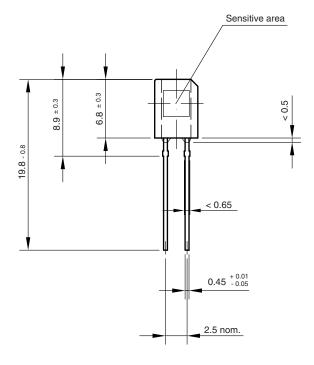
Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

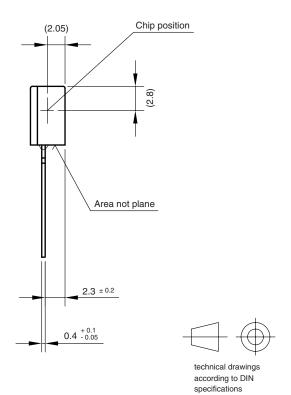


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## **PACKAGE DIMENSIONS** in millimeters







Drawing-No.: 6.544-5108.01-4

Issue:1; 01.07.96

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Document Number: 91000 www.vishay.com
Revision: 11-Mar-11 1